

Makoto Takamura

List of Publications by Year in Descending Order

Source: <https://exaly.com/author-pdf/6919373/makoto-takamura-publications-by-year.pdf>

Version: 2024-04-27

This document has been generated based on the publications and citations recorded by exaly.com. For the latest version of this publication list, visit the link given above.

The third column is the impact factor (IF) of the journal, and the fourth column is the number of citations of the article.

37
papers

347
citations

11
h-index

17
g-index

37
ext. papers

397
ext. citations

3.3
avg, IF

3.12
L-index

#	Paper	IF	Citations
37	Scanning probe analysis of twisted graphene grown on a graphene/silicon carbide template.. <i>Nanotechnology</i> , 2021 ,	3.4	1
36	Nanoscale evaluation of the number of layers of hexagonal boron nitride by scattering-type scanning near-field optical microscopy. <i>Japanese Journal of Applied Physics</i> , 2021 , 60, SBBH15	1.4	2
35	Active spatial control of terahertz plasmons in graphene. <i>Communications Materials</i> , 2020 , 1,	6	4
34	Plasmon Control Driven by Spatial Carrier Density Modulation in Graphene. <i>ACS Photonics</i> , 2019 , 6, 947-953	9.3	7
33	Self-Folded Three-Dimensional Graphene with a Tunable Shape and Conductivity. <i>Nano Letters</i> , 2019 , 19, 461-470	11.5	9
32	Unraveling localized states in quasi free standing monolayer graphene by means of Density Functional Theory. <i>Carbon</i> , 2018 , 130, 466-474	10.4	6
31	Atomic and electronic structure of Si dangling bonds in quasi-free-standing monolayer graphene. <i>Nano Research</i> , 2018 , 11, 864-873	10	12
30	Plasmon confinement by carrier density modulation in graphene. <i>Japanese Journal of Applied Physics</i> , 2018 , 57, 110307	1.4	3
29	Very Gradual and Anomalous Oxidation at the Interface of Hydrogen-Intercalated Graphene/4H-SiC(0001). <i>Journal of Physical Chemistry C</i> , 2017 , 121, 26389-26396	3.8	0
28	Effects of environmental conditions on the ultrafast carrier dynamics in graphene revealed by terahertz spectroscopy. <i>Physical Review B</i> , 2017 , 95,	3.3	11
27	Transmission, reflection, and absorption spectroscopy of graphene microribbons in the terahertz region. <i>Japanese Journal of Applied Physics</i> , 2016 , 55, 06GF08	1.4	4
26	Energy Dissipation in Graphene Mechanical Resonators with and without Free Edges. <i>Micromachines</i> , 2016 , 7,	3.3	8
25	Direct growth of graphene on SiC(0001) by KrF-excimer-laser irradiation. <i>Applied Physics Letters</i> , 2016 , 108, 093107	3.4	6
24	Applying strain into graphene by SU-8 resist shrinkage. <i>Journal Physics D: Applied Physics</i> , 2016 , 49, 285303	3	2
23	Graphene FRET Aptasensor. <i>ACS Sensors</i> , 2016 , 1, 710-716	9.2	23
22	Bilayer-induced asymmetric quantum Hall effect in epitaxial graphene. <i>Semiconductor Science and Technology</i> , 2015 , 30, 055007	1.8	5
21	Effects of UV light intensity on electrochemical wet etching of SiC for the fabrication of suspended graphene. <i>Japanese Journal of Applied Physics</i> , 2015 , 54, 036502	1.4	3

20	Correlation between morphology and transport properties of quasi-free-standing monolayer graphene. <i>Applied Physics Letters</i> , 2014 , 105, 221604	3.4	18
19	Energy dissipation in edged and edgeless graphene mechanical resonators. <i>Journal of Applied Physics</i> , 2014 , 116, 064304	2.5	8
18	Effects of hydrogen intercalation on transport properties of quasi-free-standing monolayer graphene. <i>Japanese Journal of Applied Physics</i> , 2014 , 53, 04EN01	1.4	16
17	Hydrogen storage with titanium-functionalized graphene. <i>Applied Physics Letters</i> , 2013 , 103, 013903	3.4	47
16	Structural Instability of Transferred Graphene Grown by Chemical Vapor Deposition against Heating. <i>Journal of Physical Chemistry C</i> , 2013 , 117, 22123-22130	3.8	21
15	Epitaxial Trilayer Graphene Mechanical Resonators Obtained by Electrochemical Etching Combined with Hydrogen Intercalation. <i>Japanese Journal of Applied Physics</i> , 2013 , 52, 04CH01	1.4	11
14	Self organization of a hexagonal network of quasi-free-standing monolayer graphene nanoribbons. <i>Physical Review B</i> , 2013 , 87,	3.3	3
13	Selective charge doping of chemical vapor deposition-grown graphene by interface modification. <i>Applied Physics Letters</i> , 2013 , 103, 253116	3.4	14
12	Tuning of quantum interference in top-gated graphene on SiC. <i>Physical Review B</i> , 2013 , 88,	3.3	14
11	Graphene-modified interdigitated array electrode: fabrication, characterization, and electrochemical immunoassay application. <i>Analytical Sciences</i> , 2013 , 29, 55-60	1.7	22
10	Quantum Hall Effect and Carrier Scattering in Quasi-Free-Standing Monolayer Graphene. <i>Applied Physics Express</i> , 2012 , 5, 125101	2.4	23
9	Matching field effects in c-axis in-plane aligned a-axis-oriented YBa ₂ Cu ₃ O _y films with two-dimensional artificial pinning centers induced by multilayered nano-structures. <i>Superconductor Science and Technology</i> , 2010 , 23, 045023	3.1	5
8	Fabrication and characteristics of artificial SNS junctions using three axes orientation-controlled a-axis oriented Y123/Pr123 multilayer films. <i>Journal of Physics: Conference Series</i> , 2010 , 234, 012044	0.3	2
7	Microstructures of REBa ₂ Cu ₃ O _y films containing artificial pinning centers of various dimensions. <i>Physica C: Superconductivity and Its Applications</i> , 2009 , 469, 1374-1379	1.3	7
6	Effects of the APC materials on c-axis correlated pinning effects in a-axis oriented Y123/2D APC multilayer films. <i>Physica C: Superconductivity and Its Applications</i> , 2009 , 469, 1545-1549	1.3	3
5	Vortex Behaviors Near Irreversibility Fields of a-Axis Oriented Y123 Films Inserted Pr123 Layers. <i>IEEE Transactions on Applied Superconductivity</i> , 2009 , 19, 3499-3502	1.8	1
4	Two-dimensional vortex-pinning phenomena in YBa ₂ Cu ₃ O _y films. <i>Applied Physics Letters</i> , 2008 , 92, 132502	3.4	14
3	A novel 2-dimensional artificial pinning center. <i>Journal of Physics: Conference Series</i> , 2008 , 97, 012153	0.3	

2	Electrical transport properties of Y123 films with 2-D apcs. <i>Physica C: Superconductivity and Its Applications</i> , 2008 , 468, 1851-1853	1-3	5
1	A new approach to a two-dimensional artificial pinning center. <i>Physica C: Superconductivity and Its Applications</i> , 2007 , 463-465, 904-908	1-3	7